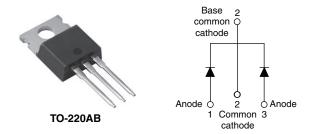


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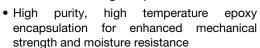
Schottky Rectifier, 2 x 20 A



PRODUCT SUMMARY					
Package	TO-220AB				
I _{F(AV)}	2 x 20 A				
V _R	60 V				
V _F at I _F	0.58 V				
I _{RM}	89 mA at 125 °C				
T _J max.	150 °C				
Diode variation	Common cathode				
E _{AS}	13 mJ				

FEATURES

• Low forward voltage drop





RoHS*

- Guard ring for enhanced ruggedness and long term reliability
- 150 °C T_J operation
- Center tap configuration
- High frequency operation
- Compliant to RoHS directive 2002/95/EC
- Designed and qualified for industrial level

DESCRIPTION

This center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL CHARACTERISTICS VALUES UNITS						
I _{F(AV)}	Rectangular waveform	40	A			
V _{RRM}		60	V			
I _{FSM}	t _p = 5 μs sine	1000	A			
V _F	20 Apk, T _J = 125 °C (per leg)	0.58	V			
T _J	Range	- 55 to 150	°C			

VOLTAGE RATINGS							
PARAMETER SYMBOL VS-48CTQ060PbF UNITS							
Maximum DC reverse voltage	ge V _R 60 V						
Maximum working peak reverse voltage	V_{RWM}	00	V				

ABSOLUTE MAXIMUM RATINGS							
PARAMETER		SYMBOL	TEST CONDI	TIONS	VALUES	UNITS	
Maximum average forward current	per leg	I	50 % duty cycle at T _C = 111 °C, rectangular waveform		20		
See fig. 5	per device	I _{F(AV)}	30 % duty cycle at 1 _C = 111 C	o, rectangular wavelomi	40	A	
Maximum peak one cycle non-repetitive surge current per leg I _F See fig. 7			5 µs sine or 3 µs rect. pulse	Following any rated load condition and with	1000] ^	
		I _{FSM}	10 ms sine or 6 ms rect. pulse	rated V _{RRM} applied	260		
Non-repetitive avalanche energy per leg		E _{AS}	T _J = 25 °C, I _{AS} = 1.50 A, L = 11.5 mH		13	mJ	
Repetitive avalanche current per leg		I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		1.50	А	

^{*} Pb containing terminations are not RoHS compliant, exemptions may apply

VS-48CTQ060PbF

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ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS		
		20 A	T _{.1} = 25 °C	0.61	V	
Maximum forward voltage drop per leg	V _{FM} ⁽¹⁾	40 A	1J=25 C	0.83		
See fig. 1	VFM (1)	20 A	T. = 125 °C	0.58		
		40 A	1J = 125 C	0.75		
Maximum reverse leakage current per leg	I _{RM} ⁽¹⁾	T _J = 25 °C	V Detectiv	2	mA	
See fig. 2		T _J = 125 °C	V _R = Rated V _R	89		
Threshold voltage	V _{F(TO)}	T T manimum		0.37	V	
Forward slope resistance	r _t	$T_J = T_J$ maximum		8.26	mΩ	
Maximum junction capacitance per leg	C _T	V_R = 5 V_{DC} (test signal range 100 kHz to 1 MHz), 25 °C		1220	pF	
Typical series inductance per leg	L _S	Measured lead to lead 5 mm from package body		8.0	nH	
Maximum voltage rate of change	dV/dt	Rated V _R			V/µs	

Note

 $^{^{(1)}\,}$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range	9	T _J , T _{Stg}		- 55 to 150	°C	
Maximum thermal resistance, junction to case per leg	,			2.0		
Maximum thermal resistance, junction to case per package		R _{thJC}	DC operation	1.0	°C/W	
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.50		
Approximate weight				2	g	
Approximate weight				0.07	OZ.	
Mounting torque	minimum			6 (5)	kgf · cm	
Mounting torque -	maximum			12 (10)	(lbf \cdot in)	
Marking device			Case style TO-220AB	48CT	Q060	



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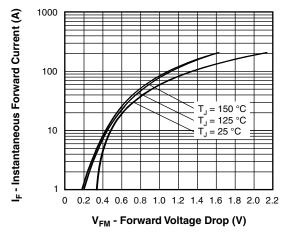


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

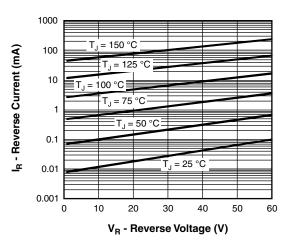


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

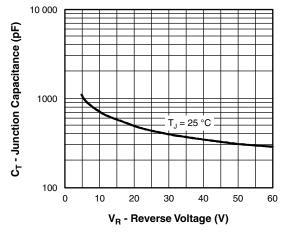


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

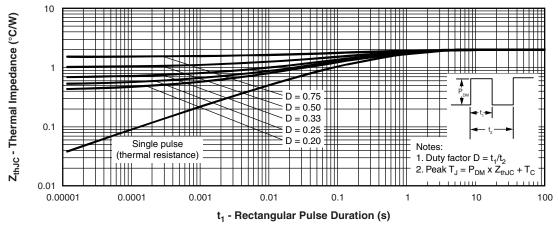


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

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Schottky Rectifier, 2 x 20 A



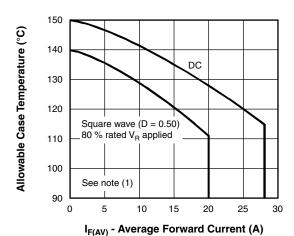


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

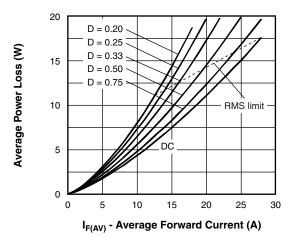


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

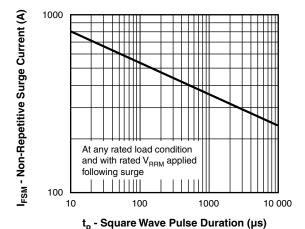


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

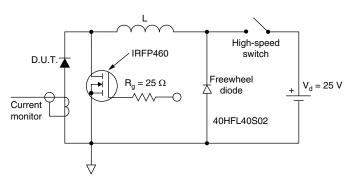


Fig. 8 - Unclamped Inductive Test Circuit

Note

 $^{(1)}$ Formula used: $T_C = T_J$ - (Pd + Pd_{REV}) x R_{thJC}; Pd = Forward power loss = $I_{F(AV)}$ x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = Inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = 10 V

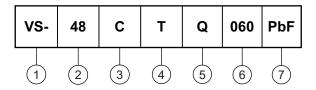


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ORDERING INFORMATION TABLE

Device code



- 1 Vishay Semiconductors product
- Current rating (40 A)
- Circuit configuration:

C = Common cathode

4 - Package:

T = TO-220

5 - Schottky "Q" series

6 - Voltage rating (060 = 60 V)

- None = Standard production

• PbF = Lead (Pb)-free

Tube standard pack quantity: 50 pieces

LINKS TO RELATED DOCUMENTS					
Dimensions <u>www.vishay.com/doc?95222</u>					
Part marking information	www.vishay.com/doc?95225				
SPICE model	www.vishay.com/doc?95424				



Vishay Semiconductors

TO-220AB

DIMENSIONS in millimeters and inches



Lead assignments

Diodes

- 1. Anode/open
- 2. Cathode
- 3. Anode

Conforms to JEDEC outline TO-220AB

SYMBOL	MILLIN	IETERS	INCHES		NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.56	2.92	0.101	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.25	0.585	0.600	3
D1	8.38	9.02	0.330	0.355	
D2	11.68	12.88	0.460	0.507	6

SYMBOL	MILLIM	IETERS	INCHES		NOTES
STIMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
E	10.11	10.51	0.398	0.414	3, 6
E1	6.86	8.89	0.270	0.350	6
E2	-	0.76	-	0.030	7
е	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6, 7
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
ØΡ	3.54	3.73	0.139	0.147	
Q	2.60	3.00	0.102	0.118	
θ	90° to 93°		90° to 93°		
		•	•	•	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1
- (7) Dimensions E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC TO-220, except A2 (maximum) and D2 (minimum) where dimensions are derived from the actual package outline

Lead tip





Vishay

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